



SANYO Semiconductors

DATA SHEET

CPH3143 / CPH3243

— PNP / NPN Epitaxial Planar Silicon Transistors

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package permitting applied sets to be small and slim (mounting height : 0.9mm).
- High allowable power dissipation.

Specifications () : CPH3143

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)15	V
Collector-to-Emitter Voltage	V _{CEO}		(-12)15	V
Emitter-to-Base Voltage	V _{EBO}		(-)5	V
Collector Current	I _C		(-)2.5	A
Collector Current (Pulse)	I _{CP}		(-)5	A
Base Current	I _B		(-)500	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² X0.8mm)	0.9	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =(-)12V, I _E =0			(-)0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)0.1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)100mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)2V, I _C =(-)300mA		370		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(22)16		pF

Marking : CPH3143 : BC, CPH3243 : DN

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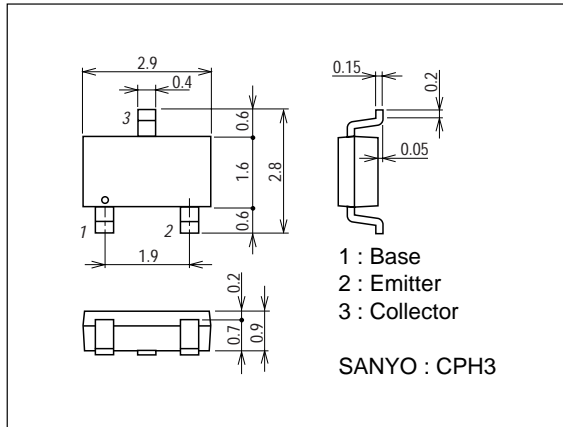
CPH3143 / CPH3243

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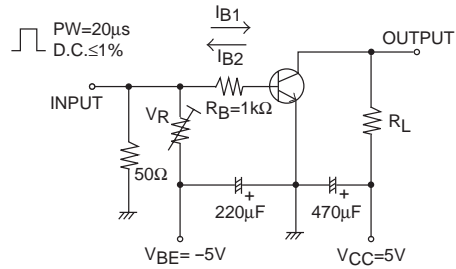
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1A, I_B=(-)50mA$		(-90)100	(-135)150	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)1A, I_B=(-)50mA$		(-)0.89	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-15)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-12)15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(35)30		ns
Storage Time	t_{stg}	See specified Test Circuit.		(110)180		ns
Fall Time	t_f	See specified Test Circuit.		(15)13		ns

Package Dimensions

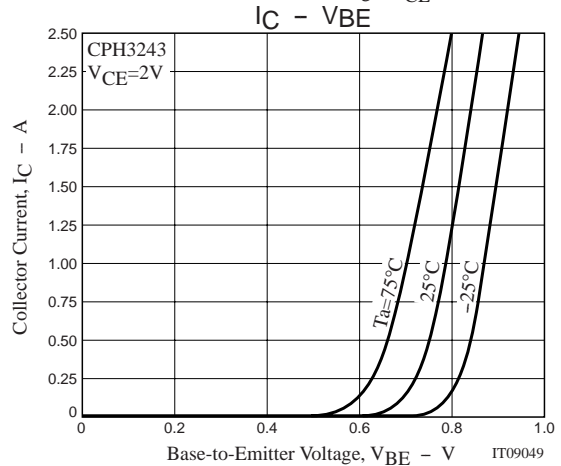
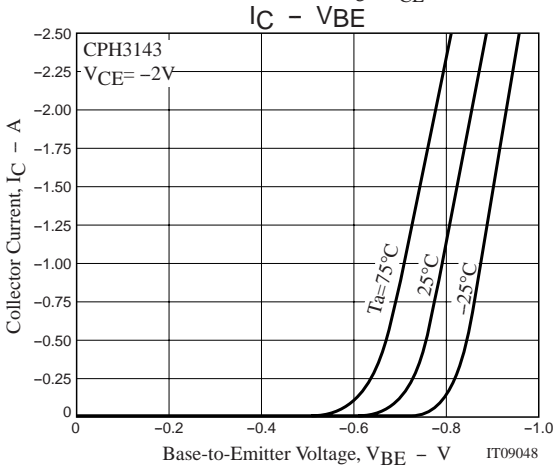
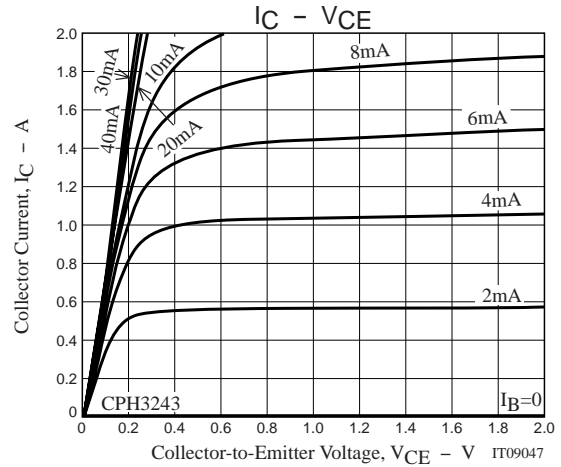
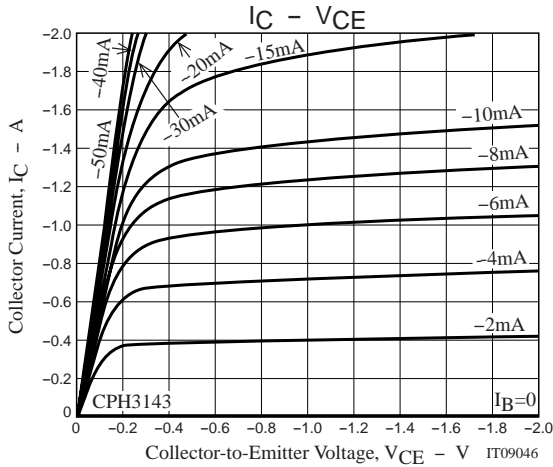
unit : mm
2150A

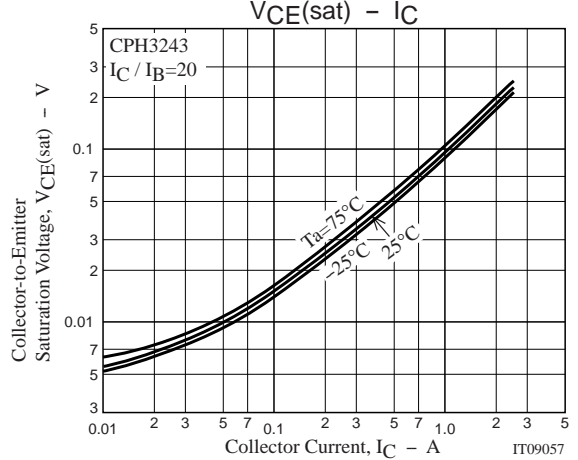
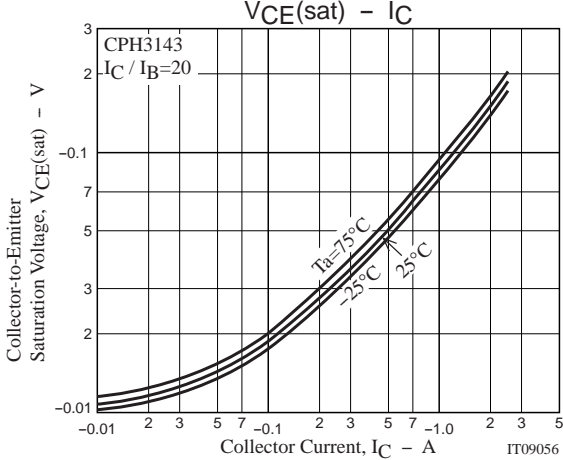
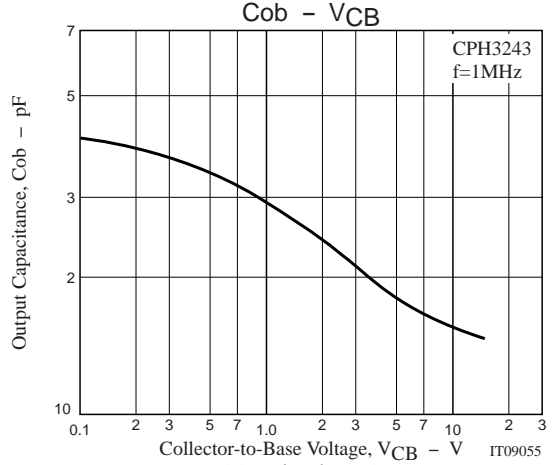
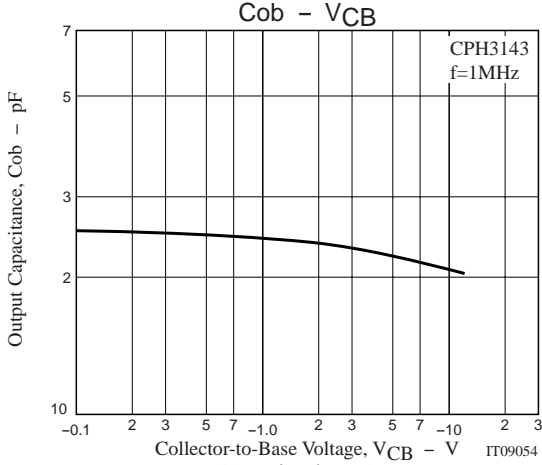
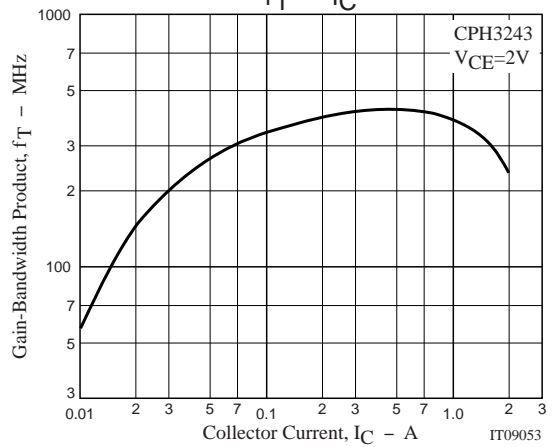
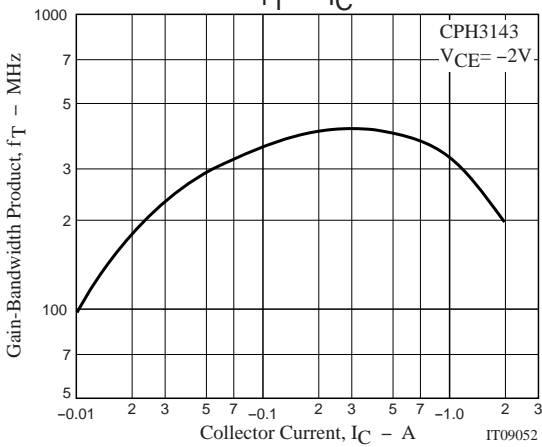
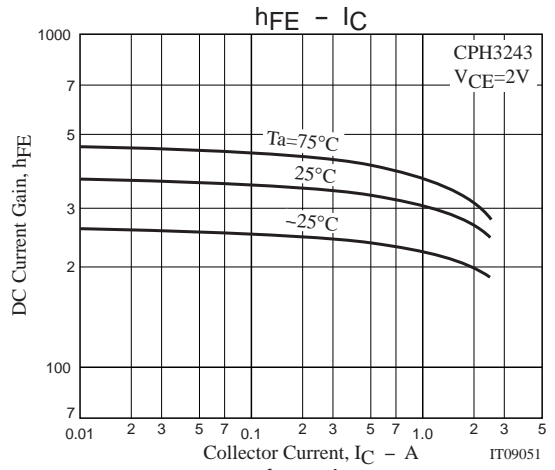
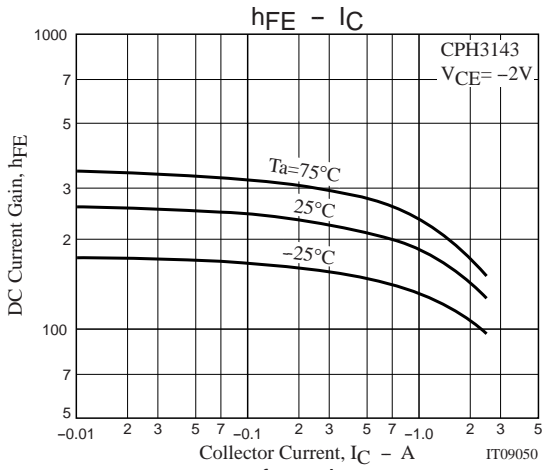


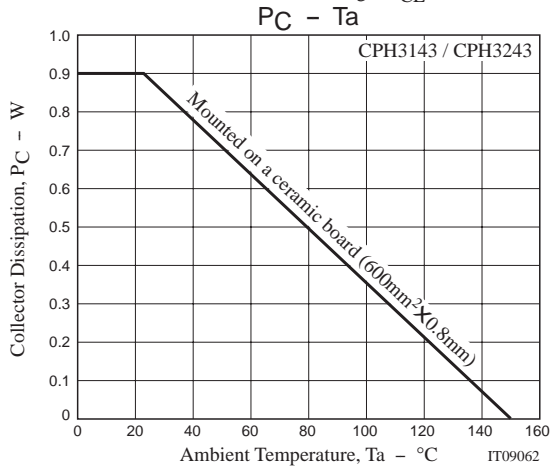
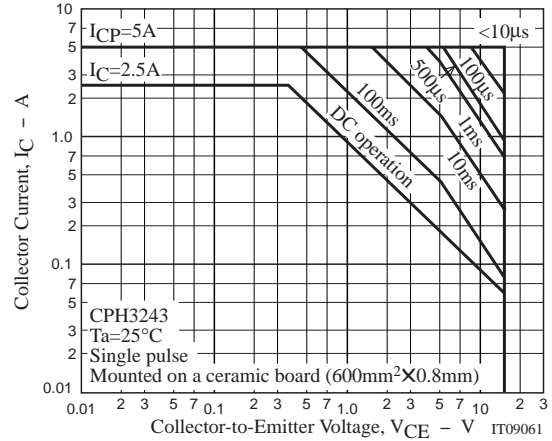
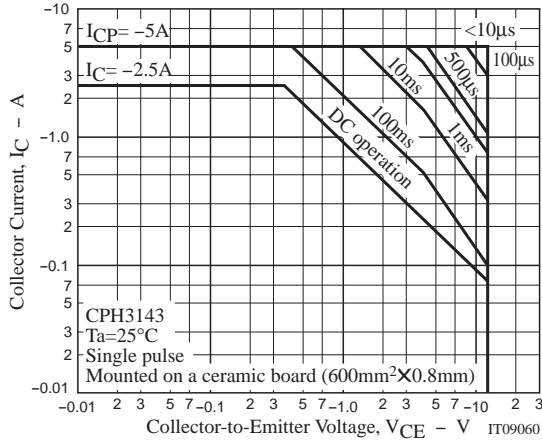
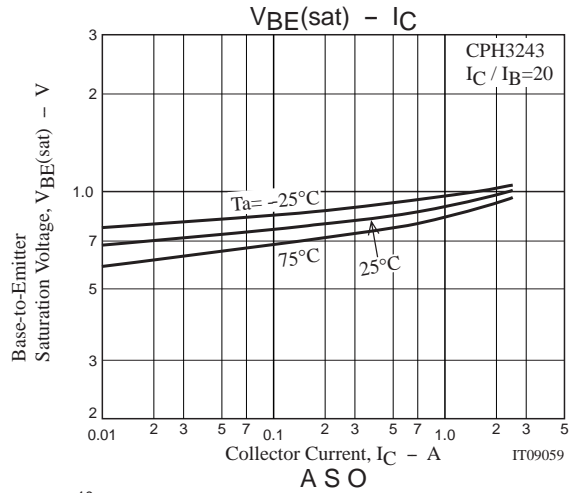
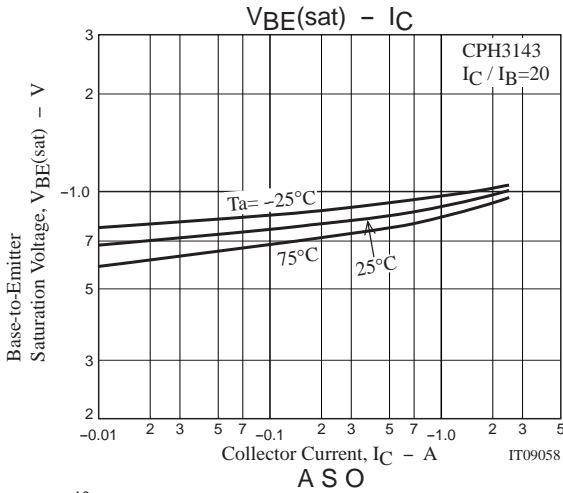
Switching Time Test Circuit



$I_C=20I_{B1}=-20I_{B2}=1A$
For PNP, the polarity is reversed.







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